

R6030ENZ1C9 Information


For Reference Only

Part Number [R6030ENZ1C9](#)
Manufacturer Rohm Semiconductor
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - Single](#)
Description MOSFET N-CH 600V 30A TO247
Package TO-247-3
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


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Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


R6030ENZ1C9 Specifications

Manufacturer Part Number	R6030ENZ1C9
Manufacturer	Rohm Semiconductor
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vds)	600V
Current - Continuous Drain (Id) @ 25°C	30A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	85nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	2100pF @ 25V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	120W (Tc)
Rds On (Max) @ Id, Vgs	130 mOhm @ 14.5A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-247
Package / Case	TO-247-3

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R6030ENZ1C9 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

R6030ENZ1C9 Payment Methods



R6030ENZ1C9 Shipping Methods



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